

Features

- Glass Passivated Die Construction
- Ultra-Fast Recovery Time for High Efficiency
- High Maximum Junction Temperature
- High Forward Surge Current Capability
- **Lead Free Finish, RoHS Compliant (Note 1)**
- **"Green" Molding Compound (No Br, Sb)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

- Case: PowerDI™5
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish – Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 (e3)
- Polarity: See Diagram on Page 4
- Marking Information: See Page 3
- Ordering Information: See Page 3
- Weight: 0.096 grams (approximate)



TOP VIEW



BOTTOM VIEW

Maximum Ratings @ T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	200	V
RMS Reverse Voltage	$V_{R(RMS)}$	141	V
Average Rectified Output Current (See also figure 4)	I_O	3 6	A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave Superimposed on Rated Load per element	I_{FSM}	90	A

Thermal Characteristics

Characteristic	Symbol	Typ	Max	Unit
Thermal Resistance Junction to Soldering Point	$R_{\theta JS}$	—	3.0	°C/W
Thermal Resistance Junction to Ambient Air (Note 2)	$R_{\theta JA}$	80	—	°C/W
Thermal Resistance Junction to Ambient Air (Note 3)	$R_{\theta JA}$	65	—	°C/W
Thermal Resistance Junction to Ambient Air (Note 4)	$R_{\theta JA}$	45	—	°C/W
Operating Temperature Range	T_J	-65 to +175		°C
Storage Temperature Range	T_{STG}	-65 to +175		°C

- Notes:
1. RoHS revision 13.2.2003. Glass and High Temperature Solder Exemptions Applied, see *EU Directive Annex Notes 5 and 7*.
 2. FR-4 PCB, 2 oz. Copper, minimum recommended pad layout per <http://www.diodes.com/datasheets/ap02001.pdf>.
 3. Polyimide PCB, 2 oz. Copper, minimum recommended pad layout per <http://www.diodes.com/datasheets/ap02001.pdf>.
 4. Polyimide PCB, 2 oz. Copper. Cathode pad dimensions 9.4mm x 7.2mm. Anode pad dimensions 2.7mm x 1.6mm.

Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Value	Unit	Test Condition
Minimum Reverse Breakdown Voltage (Note 5)	$V_{(BR)R}$	200	V	$I_R = 5\mu\text{A}$
Maximum Forward Voltage per element	V_{FM}	1.00 0.96 1.20 1.13	V	$I_F = 3\text{A}$, $T_S = 25^\circ\text{C}$ $I_F = 3\text{A}$, $T_S = 125^\circ\text{C}$ $I_F = 6\text{A}$, $T_S = 25^\circ\text{C}$ $I_F = 6\text{A}$, $T_S = 125^\circ\text{C}$
Maximum Reverse Leakage Current per element (Note 5)	I_{RM}	5 250	μA	$T_S = 25^\circ\text{C}$, $V_R = 200\text{V}$ $T_S = 125^\circ\text{C}$, $V_R = 200\text{V}$
Maximum Reverse Recovery Time	t_{rr}	25	ns	$I_F = 0.5\text{A}$, $I_R = 1.0\text{A}$ $I_{RR} = 0.25\text{A}$ (See figure 7)

Notes: 5. Short duration test pulse used to minimize self-heating effect.

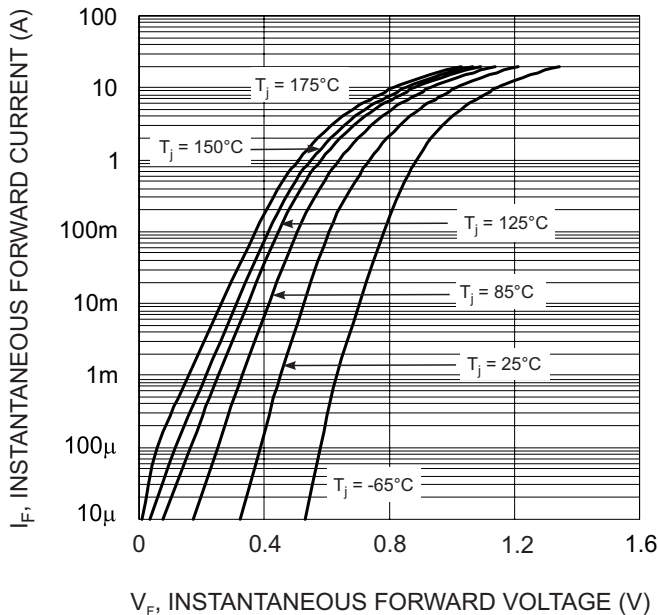


Fig. 1 Typical Forward Characteristics, per element

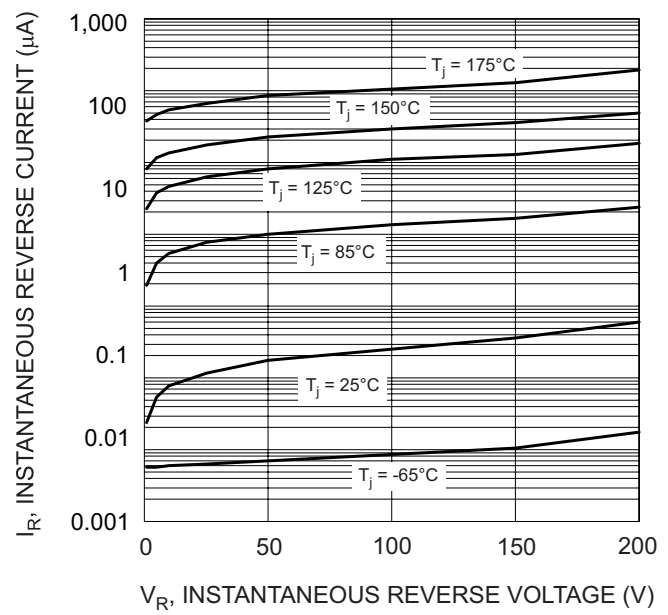


Fig. 2 Typical Reverse Characteristics, per element

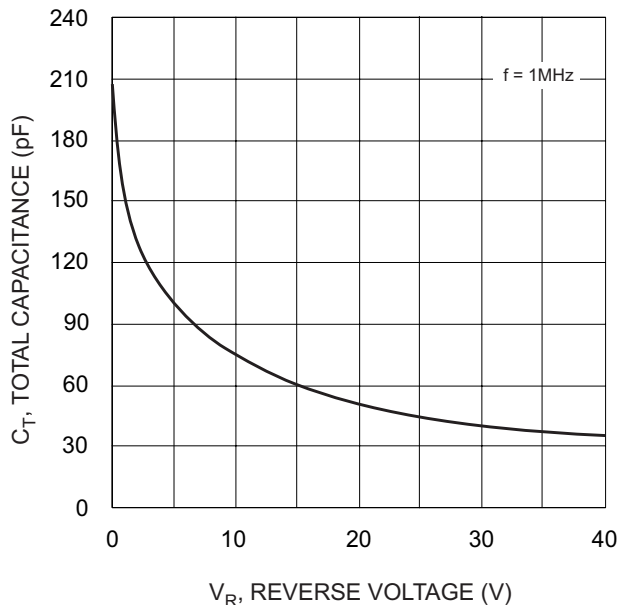


Fig. 3 Typical Total Capacitance vs. Reverse Voltage, per element

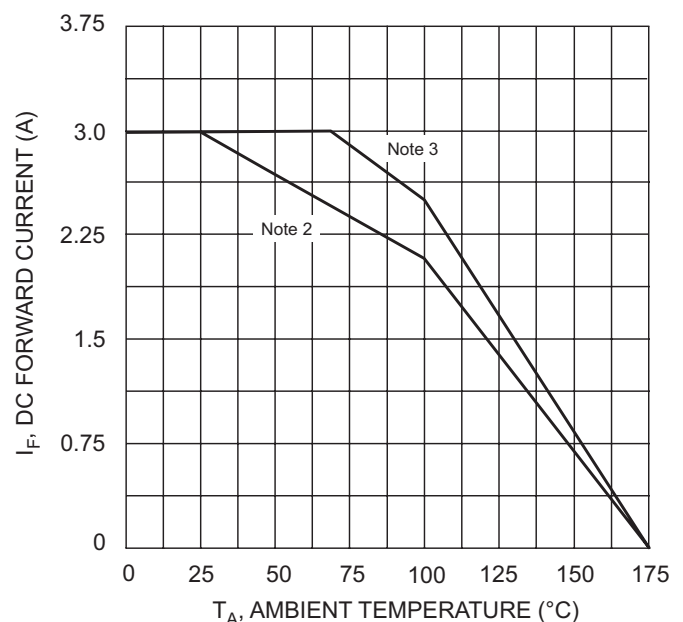


Fig. 4 DC Forward Current Derating, per element

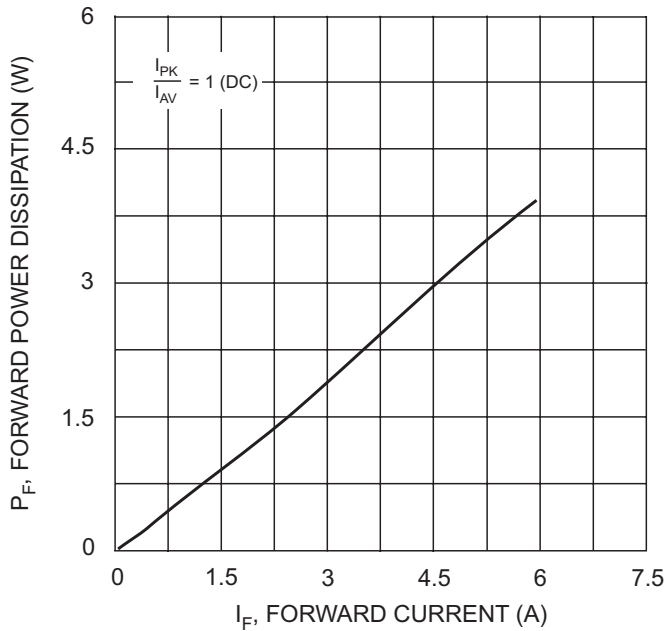


Fig. 5 Forward Power Dissipation, per element

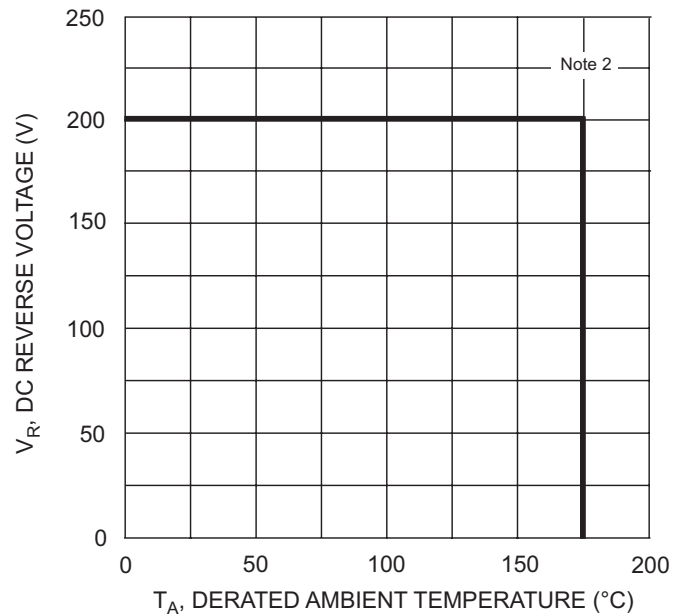
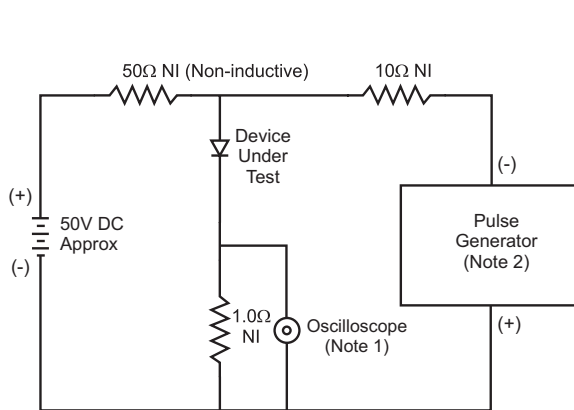
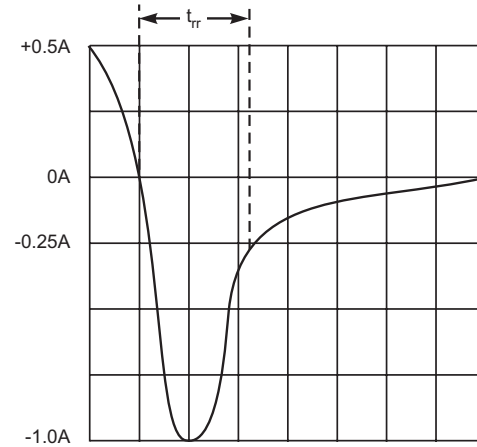


Fig. 6 Operating Temperature Derating



Notes:

1. Rise Time = 7.0ns max. Input Impedance = 1.0MΩ, 22pF.
2. Rise Time = 10ns max. Input Impedance = 50Ω.



Set time base for 50/100 ns/cm

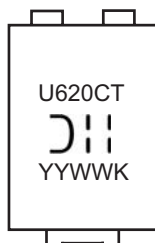
Fig. 7 Reverse Recovery Time Characteristic and Test Circuit

Ordering Information (Note 6)

Device	Packaging	Shipping
PDU620CT-13	PowerDI™5	5000/Tape & Reel

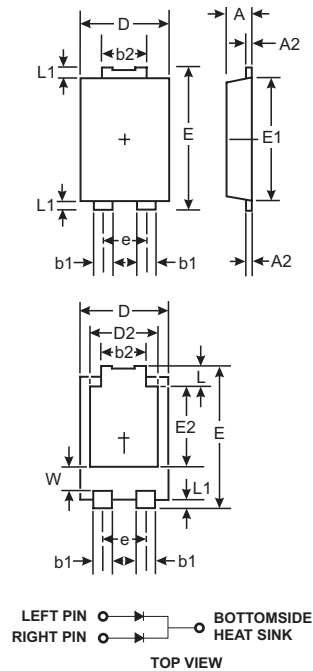
Notes: 6. For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information



U620CT = Product type marking code
 Diodes Incorporated logo = Manufacturers' code marking
 YYWW = Date code marking
 YY = Last digit of year ex: 06 for 2006
 WW = Week code 01 to 52
 K = Factory Designator

Package Outline Dimensions



PowerDI™5		
Dim	Min	Max
A	1.05	1.15
A2	0.33	0.43
b1	0.80	0.99
b2	1.70	1.88
D	3.90	4.05
D2	3.05 NOM	
E	6.40	6.60
e	1.84 NOM	
E1	5.30	5.45
E2	3.55 NOM	
L	0.75	0.95
L1	0.50	0.65
W	1.20	1.50
All Dimensions in mm		

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<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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